

Green Products

Technical Data Data Sheet N0922, Rev. A

# SBRF20100CTL SCHOTTKY RECTIFIER

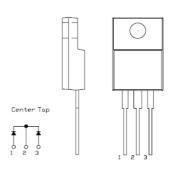
### Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

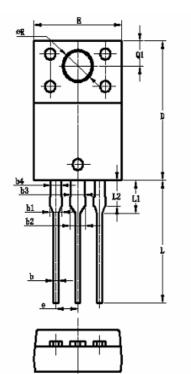
#### Features:

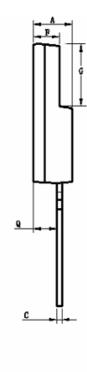
- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Mechanical Dimensions: In mm**



#### **OUTLINE DRAWING**





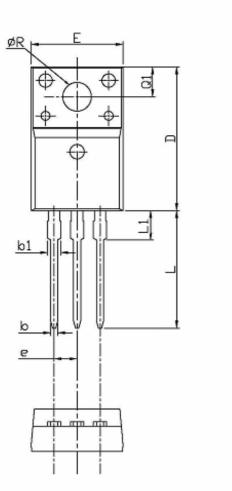
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	OPTION 1(CJ)		OPTION 2(HD)		
Dim	Min	Max	Min	Max	
Α	4.4	4.6	4.30	4.70	
b	0.61	ΥP	0.50	0.75	
b1	1.3T	ΥP	1.30	1.40	
b2	1.71	ΥP	1.70	1.80	
b3	1.6T	ΥP	1.50	1.75	
b4	1.2T	ΥP	1.10	1.35	
С	0.60TYP		0.50	0.75	
D	14.8	15.1	14.80	15.20	
Е	10.06	10.26	9.96	10.36	
е	2.55TYP		2.54TYP		
F	2.9	3.1	2.80	3.20	
G	6.5	6.9	6.50	6.90	
L	12.7	13.7	12.8	13.2	
L1	3.4	3.8	3.60	4.00	
L2	2.6	3.0	-	-	
Q	2.5	2.9	2.50	2.90	
Q1	2.5	2.5 2.9		2.70REF	
ØR	3.5REF		3.50REF		

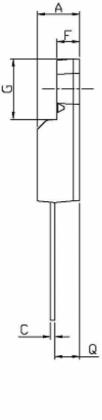
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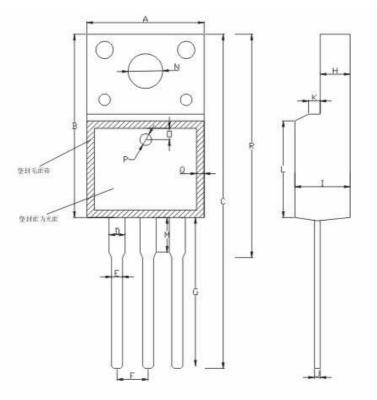




1					
	OPTI	ON 3	OPTION 4		
Dim	Min	Max	Min	Мах	
Α	4.53	4.93	4.50	4.90	
b	0.71	0.91	0.70	0.90	
b1	1.15	1.39	1.33	1.47	
С	0.36	0.53	0.45	0.60	
D	15.67	16.07	15.67	16.07	
Е	9.96	10.36	9.96	10.36	
е	2.54	ГҮР	2.54 BSC		
F	2.34	2.76	2.34	2.74	
G	6.50	6.90	6.48	6.88	
L	12.37	12.77	12.78	13.18	
L1	2.23	2.63	3.03	3.43	
Q	2.56	2.96	2.56	2.96	
Q1	3.10	3.50	3.10	3.50	
ØR	2.98	3.38	3.08	3.28	



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A:10.20	$\pm 0.50$	B:15.90	$\pm 0.50$	C:29.00	$\pm 1.00$	D:1.24	$\pm 0.10$
E:0.80	$\pm 0.10$	F:2.54	$\pm 0.10$	G:13.10	$^{\pm 1,0}$	H:2.55	$\pm 0.05$
I:4.70	$\pm 0.05$	J:0.50	$\pm 0.05$	K:1.20	$\pm 0.20$	L:8.00	$\pm 0.50$
M:3.00	$\pm 0.50$	N:3.20	$\pm 0.20$	O:1,25	$\pm 0.05$	P:1.5	$\pm 0.05$
Q:1.0	±0.20	R:19.2	$\pm 1.0$				

### **OPTION 5 (SR)**

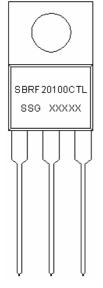
ITO-220AB



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### **Green Products**

### Marking Diagram:



Where XXXXX is YYWWL

SBR	= Device Type
F	= Package type
20	= Forward Current (20A)
100	= Reverse Voltage (100V)
CTL	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

### **Ordering Information:**

Device	Package	Shipping
SBRF20100CTL	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	100	V
Max. Average Forward (per leg)	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =133℃, rectangular wave form	20	A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	150	А

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@ 10 A, Pulse, T <sub>C</sub> = 25 °C	0.94	V
(per leg) *	V <sub>F2</sub>	@ 10 A, Pulse, T <sub>C</sub> = 125 °C	0.78	V
Max. Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = rated V_R$ T <sub>C</sub> = 25 °C	1.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R$ T <sub>C</sub> = 125 °C	6.0	mA
Max. Junction Capacitance (per leg)	C <sub>T</sub>	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C f <sub>SIG</sub> = 1MHz	400	pF
Typical Series Inductance (per leg)	L <sub>S</sub>	Measured lead to lead 5 mm from package body	8.0	nH
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs

\* Pulse Width < 300µs, Duty Cycle <2%

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	ΤJ	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ extsf{ heta}JC}$	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



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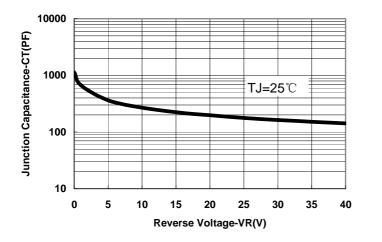


Fig.1-Typical Junction Capacitance Vs.Reverse Voltage

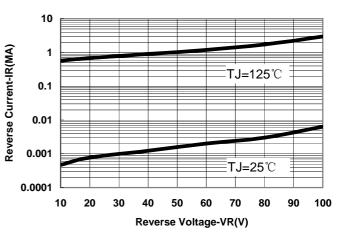


Fig.2-Typical Values Of Reverse Current VS.Reverse Voltage

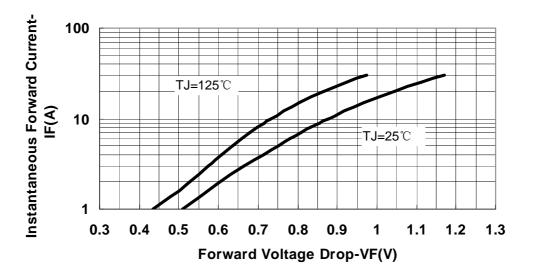


Fig.3-Typical Forward Voltage Drop Characteristics

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